

Smart High-Side Power Switch

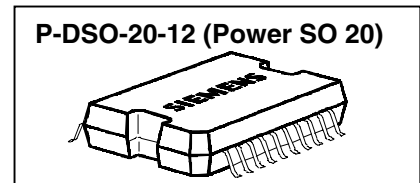
Two Channels: 2 x 30mΩ

Current Sense

Product Summary

Operating Voltage	$V_{bb(on)}$	5.0...34V	
	Active channels:	one	two parallel
On-state Resistance	R_{ON}	30mΩ	15mΩ
Load Current (ISO)	$I_{L(ISO)}$	12A	24A
Current Limitation	$I_{L(SCr)}$	24A	24A

Package



General Description

- N channel vertical power MOSFET with charge pump, ground referenced CMOS compatible input, diagnostic feedback and proportional load current sense monolithically integrated in Smart SIPMOS® technology.
- Fully protected by embedded protection functions

Applications

- μ C compatible high-side power switch with diagnostic feedback for 12V and 24V grounded loads
- All types of resistive, inductive and capacitive loads
- Most suitable for loads with high inrush currents, so as lamps
- Replaces electromechanical relays, fuses and discrete circuits

Basic Functions

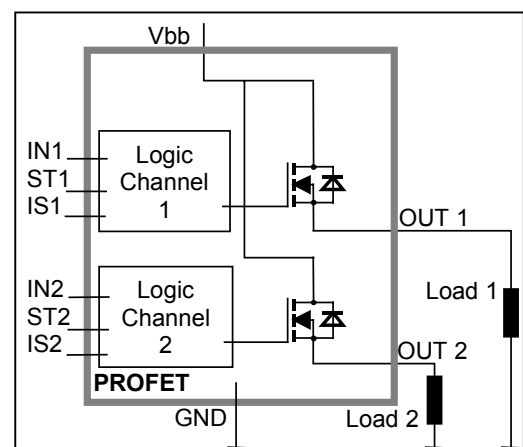
- CMOS compatible input
- Undervoltage and overvoltage shutdown with auto-restart and hysteresis
- Fast demagnetization of inductive loads
- Logic ground independent from load ground

Protection Functions

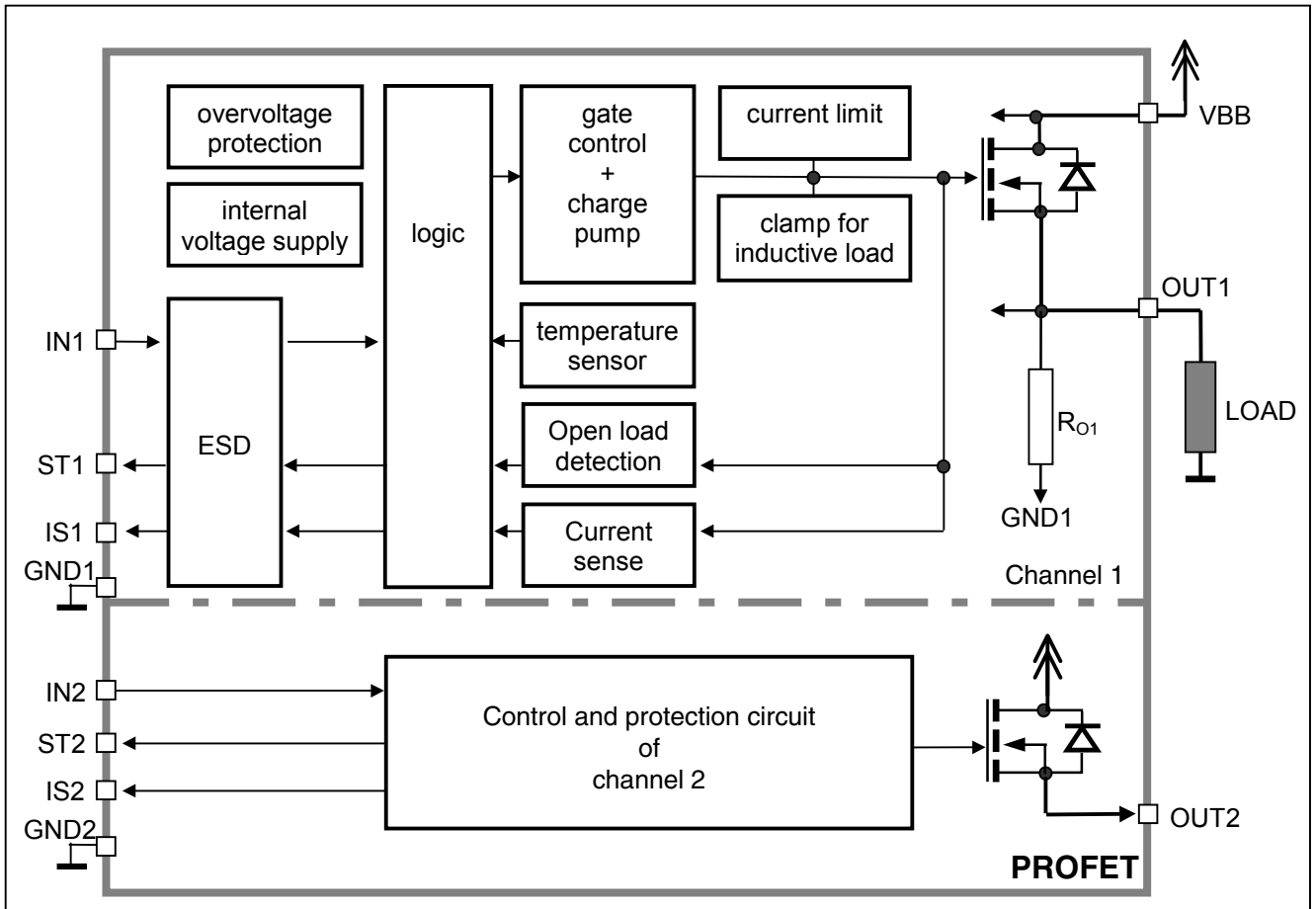
- Short circuit protection
- Overload protection
- Current limitation
- Thermal shutdown
- Overvoltage protection (including load dump) with external resistor
- Reverse battery protection with external resistor
- Loss of ground and loss of V_{bb} protection
- Electrostatic discharge protection (ESD)

Diagnostic Functions

- Proportional load current sense
- Diagnostic feedback with open drain output
- Open load detection in OFF-state with external resistor
- Feedback of thermal shutdown in ON-state



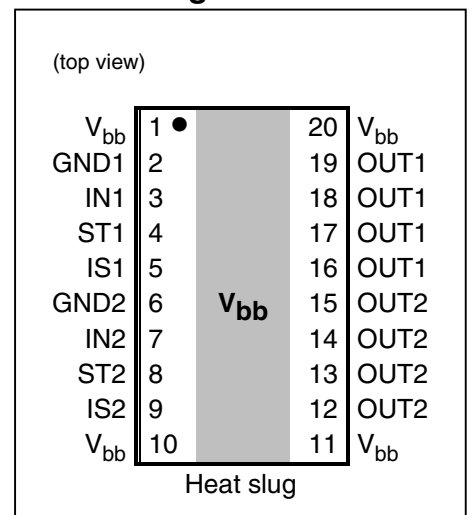
Functional diagram



Pin Definitions and Functions

Pin	Symbol	Function
1,10, 11,12,	V_{bb}	Positive power supply voltage. For high current applications the heat slug should be used as V_{bb} connection.
3	IN1	Input 1,2, activates channel 1,2 in case of logic high signal
7	IN2	
16,17, 18,19	OUT1	Output 1,2, protected high-side power output of channel 1,2. All pins of each output have to be connected in parallel for operation according this spec (e.g. k_{ijIS}). Design the wiring for the max. short circuit current
12,13, 14,15	OUT2	
4	ST1	Diagnostic feedback 1,2 of channel 1,2 open drain, invers to input level
8	ST2	
2	GND1	Ground 1,2 of chip channel 1,2
6	GND2	
5	IS1	Sense current output 1,2; proportional to the load current, zero in the case of current limitation of the load current
9	IS2	
Heatslug	V_{bb}	Positiv powersupply voltage. Good way to design a very low thermal resistance.

Pin configuration



Maximum Ratings at $T_j = 25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Values	Unit
Supply voltage (overvoltage protection see page 4)	V_{bb}	43	V
Supply voltage for full short circuit protection $T_{j,start} = -40 \dots +150^\circ\text{C}$	V_{bb}	34	V
Load current (Short-circuit current, see page 6)	I_L	self-limited	A
Load dump protection ¹⁾ $V_{LoadDump} = V_A + V_s$, $V_A = 13.5\text{ V}$ $R_l^{2)} = 2\ \Omega$, $t_d = 200\text{ ms}$; IN = low or high, each channel loaded with $R_L = 1.0\ \Omega$,	$V_{Load\ dump}^{3)}$	60	V
Operating temperature range	T_j	-40 ... +150	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55 ... +150	$^\circ\text{C}$
Power dissipation (DC) ⁴⁾ (all channels active)	$T_a = 25^\circ\text{C}$: $T_a = 85^\circ\text{C}$: P_{tot}	3.8 2.0	W
Maximal switchable inductance, single pulse $V_{bb} = 12\text{ V}$, $T_{j,start} = 150^\circ\text{C}^{4)}$, $I_L = 4\text{ A}$, $E_{AS} = 1.13\text{ J}$, $0\ \Omega$ one channel: $I_L = 12\text{ A}$, $E_{AS} = 430\text{ mJ}$, $0\ \Omega$ one channel: $I_L = 24\text{ A}$, $E_{AS} = 800\text{ mJ}$, $0\ \Omega$ two parallel channels: see diagrams on page 11	Z_L	100 4.4 2.0	mH
Electrostatic discharge capability (ESD) (Human Body Model) IN: ST, IS: out to all other pins shorted: acc. MIL-STD883D, method 3015.7 and ESD assn. std. S5.1-1993 $R=1.5\text{ k}\Omega$; $C=100\text{ pF}$	V_{ESD}	1.0 4.0 8.0	kV
Input voltage (DC)	V_{IN}	-10 ... +16	V
Current through input pin (DC)	I_{IN}	± 2.0	mA
Current through status pin (DC)	I_{ST}	± 5.0	
Current through current sense pin (DC) see internal circuit diagram page 10	I_{IS}	± 14	

- 1) Supply voltages higher than $V_{bb(AZ)}$ require an external current limit for the GND and status pins a $150\ \Omega$ resistor for the GND connection is recommended.
- 2) R_l = internal resistance of the load dump test pulse generator
- 3) $V_{Load\ dump}$ is set up without the DUT connected to the generator per ISO 7637-1 and DIN 40839
- 4) Device on $50\text{ mm} \times 50\text{ mm} \times 1.5\text{ mm}$ epoxy PCB FR4 with 6 cm^2 (one layer, $70\ \mu\text{m}$ thick) copper area for V_{bb} connection. PCB is vertical without blown air.

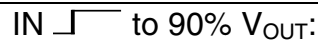
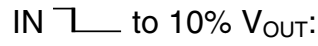
Thermal Characteristics

Parameter and Conditions	Symbol	Values			Unit
		min	typ	max	
Thermal resistance junction -case	R_{thjs}	--	--	1	K/W
junction - ambient ⁴⁾	R_{thja}	--	37	--	
each channel: one channel active: all channels active:		--	30	--	

Electrical Characteristics

Parameter and Conditions, each of the two channels at $T_j = -40\dots+150^\circ\text{C}$, $V_{bb} = 12\text{ V}$ unless otherwise specified	Symbol	Values			Unit
		min	typ	max	

Load Switching Capabilities and Characteristics

On-state resistance (V_{bb} to OUT); $I_L = 5\text{ A}$ each channel, $T_j = 25^\circ\text{C}$: $T_j = 150^\circ\text{C}$: two parallel channels, $T_j = 25^\circ\text{C}$:	R_{ON}	--	27 54 14	30 60 15	m Ω
Output voltage drop limitation at small load currents, see page 15 $I_L = 0.5\text{ A}$ $T_j = -40\dots+150^\circ\text{C}$:	$V_{ON(NL)}$	--	50	--	
Nominal load current, ISO Norm one channel active: two parallel channels active: ISO 10483-1, 6.7: $V_{on} = 0.5\text{ V}$ $T_C = 85^\circ\text{C}$	$I_{L(NOM)}$	11 22	12 24	--	A
Output current while GND disconnected or pulled up; $V_{bb} = 30\text{ V}$, $V_{IN} = 0$, see diagram page 11; (not tested specified by design)	$I_{L(GNDhigh)}$	--	--	8	mA
Turn-on time ⁵⁾ IN  to 90% V_{OUT} :	t_{on}	25	70	150	μs
Turn-off time IN  to 10% V_{OUT} : $R_L = 12\ \Omega$	t_{off}	25	80	200	
Slew rate on ⁵⁾ 10 to 30% V_{OUT} , $R_L = 12\ \Omega$:	dV/dt_{on}	0.1	--	1	V/ μs
Slew rate off ⁵⁾ 70 to 40% V_{OUT} , $R_L = 12\ \Omega$:	$-dV/dt_{off}$	0.1	--	1	V/ μs

⁵⁾ See timing diagram on page 12.

Parameter and Conditions, each of the two channels at $T_j = -40\dots+150^\circ\text{C}$, $V_{bb} = 12\text{ V}$ unless otherwise specified	Symbol	Values			Unit
		min	typ	max	

Operating Parameters

Operating voltage ⁶⁾	$V_{bb(\text{on})}$	5.0	--	34	V
Undervoltage shutdown	$V_{bb(\text{under})}$	3.2	--	5.0	V
Undervoltage restart $T_j = -40\dots+25^\circ\text{C}$: $T_j = +150^\circ\text{C}$:	$V_{bb(\text{u rst})}$	--	4.5	5.5 6.0	V
Undervoltage restart of charge pump see diagram page 14 $T_j = -40\dots+25^\circ\text{C}$: $T_j = 150^\circ\text{C}$:	$V_{bb(\text{ucp})}$	--	4.7	6.5 7.0	V
Undervoltage hysteresis $\Delta V_{bb(\text{under})} = V_{bb(\text{u rst})} - V_{bb(\text{under})}$	$\Delta V_{bb(\text{under})}$	--	0.5	--	V
Overvoltage shutdown	$V_{bb(\text{over})}$	34	--	43	V
Overvoltage restart	$V_{bb(\text{o rst})}$	33	--	--	V
Overvoltage hysteresis	$\Delta V_{bb(\text{over})}$	--	1	--	V
Overvoltage protection ⁷⁾ $I_{bb} = 40\text{ mA}$ $T_j = -40^\circ\text{C}$: $T_j = +25\dots+150^\circ\text{C}$:	$V_{bb(\text{AZ})}$	41 43	-- 47	-- 52	V
Standby current ⁸⁾ $V_{IN} = 0$; see diagram page 10 $T_j = -40^\circ\text{C}\dots25^\circ\text{C}$: $T_j = 150^\circ\text{C}$:	$I_{bb(\text{off})}$	--	8 24	30 50	μA
Leakage output current (included in $I_{bb(\text{off})}$) $V_{IN} = 0$	$I_{L(\text{off})}$	--	--	20	μA
Operating current ⁹⁾ , $V_{IN} = 5\text{V}$, $I_{GND} = I_{GND1} + I_{GND2}$, one channel on: two channels on:	I_{GND}	--	1.2 2.4	3 6	mA

Protection Functions

Current limit, (see timing diagrams, page 13) $T_j = -40^\circ\text{C}$: $T_j = 25^\circ\text{C}$: $T_j = +150^\circ\text{C}$:	$I_{L(\text{lim})}$	48 40 31	56 50 37	65 58 45	A
Repetitive short circuit current limit, $T_j = T_{jt}$ each channel two parallel channels (see timing diagrams, page 13)	$I_{L(\text{SCR})}$	-- --	24 24	-- --	A
Initial short circuit shutdown time $T_{j,\text{start}} = 25^\circ\text{C}$: (see timing diagrams on page 13)	$t_{\text{off}(\text{SC})}$	--	4.0	--	ms

6) At supply voltage increase up to $V_{bb} = 4.7\text{ V}$ typ without charge pump, $V_{OUT} \approx V_{bb} - 2\text{ V}$

7) Supply voltages higher than $V_{bb(\text{AZ})}$ require an external current limit for the GND and status pins (a $150\ \Omega$ resistor in the GND connection is recommended). See also $V_{ON(\text{CL})}$ in table of protection functions and circuit diagram page 10.

8) Measured with load; for the whole device; all channels off

9) Add I_{ST} , if $I_{ST} > 0$

Parameter and Conditions, each of the two channels at $T_j = -40\dots+150^\circ\text{C}$, $V_{bb} = 12\text{ V}$ unless otherwise specified	Symbol	Values			Unit
		min	typ	max	
Output clamp (inductive load switch off) ¹⁰⁾ at $V_{ON(CL)} = V_{bb} - V_{OUT}$, $I_L = 40\text{ mA}$ $T_j = -40^\circ\text{C}$: $T_j = 25^\circ\text{C}\dots150^\circ\text{C}$:	$V_{ON(CL)}$	41 43	-- 47	-- 52	V
Thermal overload trip temperature	T_{jt}	150	--	--	$^\circ\text{C}$
Thermal hysteresis	ΔT_{jt}	--	10	--	K

Reverse Battery

Reverse battery voltage ¹¹⁾	$-V_{bb}$	--	--	32	V
Drain-source diode voltage ($V_{out} > V_{bb}$) $I_L = -4.0\text{ A}$, $T_j = +150^\circ\text{C}$	$-V_{ON}$	--	600	--	mV

Diagnostic Characteristics

Current sense ratio ¹²⁾ , static on-condition, $V_{IS} = 0\dots5\text{ V}$, $V_{bb(on)} = 6.5^{13)}\dots27\text{V}$, $k_{ILIS} = I_L / I_{IS}$ $T_j = -40^\circ\text{C}$, $I_L = 5\text{ A}$: $T_j = -40^\circ\text{C}$, $I_L = 0.5\text{ A}$: $T_j = 25\dots+150^\circ\text{C}$, $I_L = 5\text{ A}$: $T_j = 25\dots+150^\circ\text{C}$, $I_L = 0.5\text{ A}$:	k_{ILIS}	4350 3100 4350 3800	4800 4800 4800 4800	5800 7800 5350 6300	
Current sense output voltage limitation $T_j = -40\dots+150^\circ\text{C}$ $I_{IS} = 0$, $I_L = 5\text{ A}$:	$V_{IS(lim)}$	5.4	6.1	6.9	V
Current sense leakage/offset current $T_j = -40\dots+150^\circ\text{C}$ $V_{IN}=0$, $V_{IS} = 0$, $I_L = 0$: $V_{IN}=5\text{ V}$, $V_{IS} = 0$, $I_L = 0$: $V_{IN}=5\text{ V}$, $V_{IS} = 0$, $V_{OUT} = 0$ (short circuit) ($I_{IS(SH)}$ not tested, specified by design)	$I_{IS(LL)}$ $I_{IS(LH)}$ $I_{IS(SH)}$	0 0 0	-- -- --	1 15 10	μA
Current sense settling time to $I_{IS\text{ static}}\pm 10\%$ after positive input slope, $I_L = 0 \xrightarrow{\quad} 5\text{ A}$ (not tested, specified by design)	$t_{son(IS)}$	--	--	300	μs

¹⁰⁾ If channels are connected in parallel, output clamp is usually accomplished by the channel with the lowest $V_{ON(CL)}$



¹¹⁾ Requires a $150\ \Omega$ resistor in GND connection. The reverse load current through the intrinsic drain-source diode has to be limited by the connected load. Power dissipation is higher compared to normal operating conditions due to the voltage drop across the drain-source diode. The temperature protection is not active during reverse current operation! Input and Status currents have to be limited (see max. ratings page 3 and circuit page 10).

¹²⁾ This range for the current sense ratio refers to all devices. The accuracy of the k_{ILIS} can be raised at least by a factor of two by matching the value of k_{ILIS} for every single device.
In the case of current limitation the sense current I_{IS} is zero and the diagnostic feedback potential V_{ST} is High. See figure 2c, page 13.

¹³⁾ Valid if $V_{bb(u\text{ rst})}$ was exceeded before.

Parameter and Conditions, each of the two channels at $T_j = -40\dots+150^\circ\text{C}$, $V_{bb} = 12\text{ V}$ unless otherwise specified	Symbol	Values			Unit
		min	typ	max	
Current sense settling time to 10% of I_{IS} static after negative input slope, $I_L = 5 \text{ --- } 0\text{ A}$ (not tested, specified by design)	$t_{\text{soff}(IS)}$	--	30	100	μs
Current sense rise time (60% to 90%) after change of load current $I_L = 2.5 \text{ --- } 5\text{ A}$ (not tested, specified by design)	$t_{\text{slc}(IS)}$	--	10	--	μs
Open load detection voltage ¹⁴⁾ (off-condition)	$V_{\text{OUT}(OL)}$	2	3	4	V
Internal output pull down (pin 16,17,18,19 to 2 resp. 12,13,14,15 to 6), $V_{\text{OUT}}=5\text{ V}$	R_O	5	15	40	$\text{k}\Omega$

Input and Status Feedback¹⁵⁾

Input resistance (see circuit page 10)	R_I	3.0	4.5	7.0	$\text{k}\Omega$
Input turn-on threshold voltage 	$V_{\text{IN}(T+)}$	--	--	3.5	V
Input turn-off threshold voltage 	$V_{\text{IN}(T-)}$	1.5	--	--	V
Input threshold hysteresis	$\Delta V_{\text{IN}(T)}$	--	0.5	--	V
Off state input current $V_{\text{IN}} = 0.4\text{ V}$:	$I_{\text{IN}(\text{off})}$	1	--	50	μA
On state input current $V_{\text{IN}} = 5\text{ V}$:	$I_{\text{IN}(\text{on})}$	20	50	90	μA
Delay time for status with open load after Input neg. slope (see diagram page 14)	$t_{\text{d}(\text{ST OL3})}$	--	400	--	μs
Status delay after positive input slope (not tested, specified by design)	$t_{\text{don}(\text{ST})}$	--	13	--	μs
Status delay after negative input slope (not tested, specified by design)	$t_{\text{doff}(\text{ST})}$	--	1	--	μs
Status output (open drain)					
Zener limit voltage $T_j = -40\dots+150^\circ\text{C}$, $I_{\text{ST}} = +1.6\text{ mA}$:	$V_{\text{ST}(\text{high})}$	5.4	6.1	6.9	V
ST low voltage $T_j = -40\dots+25^\circ\text{C}$, $I_{\text{ST}} = +1.6\text{ mA}$:	$V_{\text{ST}(\text{low})}$	--	--	0.4	
$T_j = +150^\circ\text{C}$, $I_{\text{ST}} = +1.6\text{ mA}$:		--	--	0.7	
Status leakage current, $V_{\text{ST}} = 5\text{ V}$, $T_j = 25 \dots +150^\circ\text{C}$:	$I_{\text{ST}(\text{high})}$	--	--	2	μA

¹⁴⁾ External pull up resistor required for open load detection in off state.

¹⁵⁾ If ground resistors R_{GND} are used, add the voltage drop across these resistors.

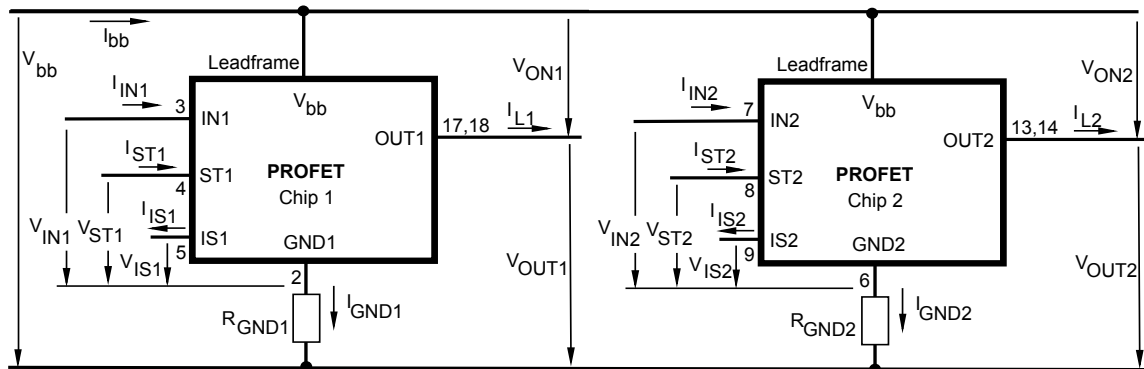
Truth Table

	Input 1	Output 1	Status 1	Current Sense 1
	Input 2	Output 2	Status 2	Current Sense 2
	level	level	level	I_{IS}
Normal operation	L	L	H	0
	H	H	L	nominal
Current-limitation	L	L	H	0
	H	H	H	0
Short circuit to GND	L	L	H	0
	H	L ¹⁶⁾	H	0
Over-temperature	L	L	H	0
	H	L	H	0
Short circuit to V_{bb}	L	H	L ¹⁷⁾	0
	H	H	L	<nominal ¹⁸⁾
Open load	L	L ¹⁹⁾	H (L ²⁰⁾)	0
	H	H	L	0
Undervoltage	L	L	H	0
	H	L	L	0
Overvoltage	L	L	H	0
	H	L	L	0
Negative output voltage clamp	L	L	H	0

L = "Low" Level X = don't care Z = high impedance, potential depends on external circuit
 H = "High" Level Status signal after the time delay shown in the diagrams (see fig 5. page 14)
 Parallel switching of channel 1 and 2 is possible by connecting the inputs and outputs in parallel. The status outputs ST1 and ST2 have to be configured as a 'Wired OR' function with a single pull-up resistor. The current sense outputs IS1 and IS2 have to be connected with a single pull-down resistor.

-
- 16) The voltage drop over the power transistor is $V_{bb} - V_{OUT} > 3V$ typ. Under this condition the sense current I_{IS} is zero
 17) An external short of output to V_{bb} , in the off state, causes an internal current from output to ground. If R_{GND} is used, an offset voltage at the GND and ST pins will occur and the $V_{ST\ low}$ signal may be errorious.
 18) Low ohmic short to V_{bb} may reduce the output current I_L and therefore also the sense current I_{IS} .
 19) Power Transistor off, high impedance
 20) with external resistor between V_{BB} and OUT

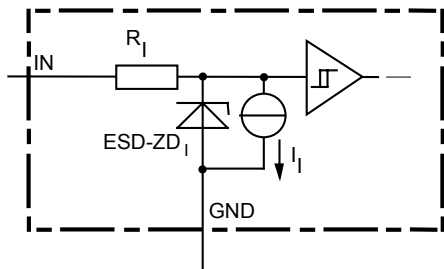
Terms



Leadframe (V_{bb}) is connected to pin 1,10,11,20

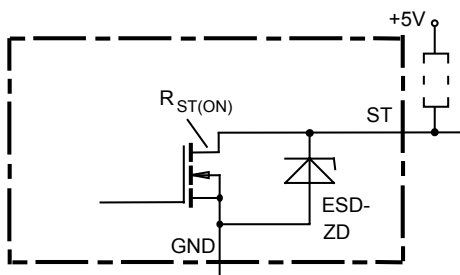
External R_{GND} optional; two resistors R_{GND1} , $R_{GND2} = 150 \Omega$ or a single resistor $R_{GND} = 75 \Omega$ for reverse battery protection up to the max. operating voltage.

Input circuit (ESD protection), IN1 or IN2



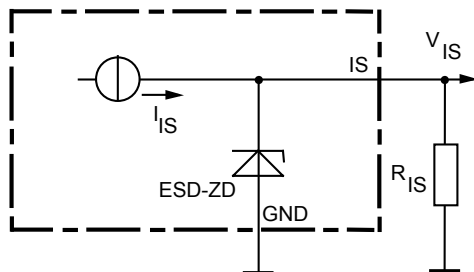
The use of ESD zener diodes as voltage clamp at DC conditions is not recommended.

Status output, ST1 or ST2



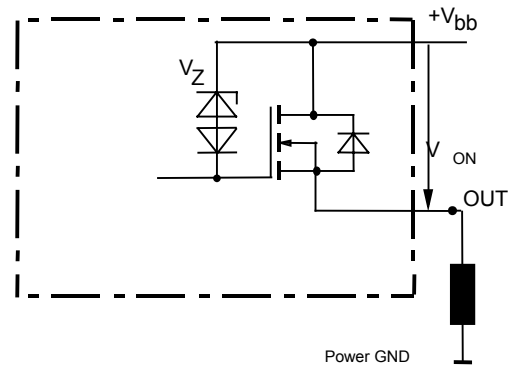
ESD-Zener diode: 6.1 V typ., max 5.0 mA; $R_{ST(ON)} < 375 \Omega$ at 1.6 mA. The use of ESD zener diodes as voltage clamp at DC conditions is not recommended.

Current sense output, IS1 or IS2



ESD-Zener diode: 6.1 V typ., max 14 mA; $R_{IS} = 1 \text{ k}\Omega$ nominal

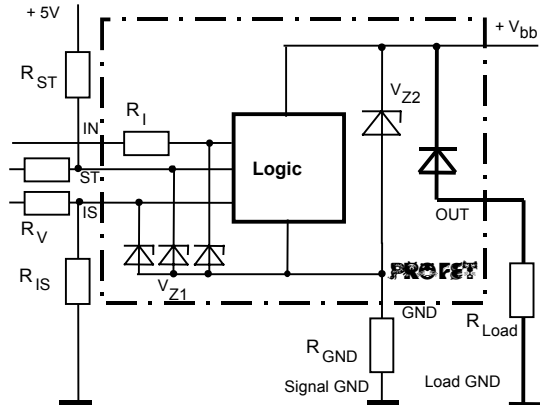
Inductive and overvoltage output clamp, OUT1 or OUT2



V_{ON} clamped to $V_{ON(CL)} = 47 \text{ V typ.}$

Overvoltage and reverse batt. Protection

For each channel

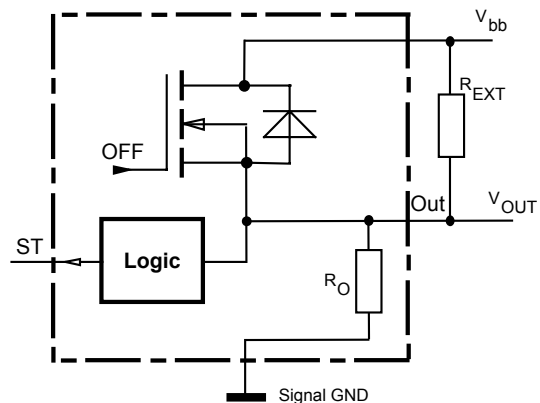


$V_{Z1} = 6.1 \text{ V typ.}$, $V_{Z2} = 47 \text{ V typ.}$, $R_{GND} = 150 \Omega$, $R_{ST} = 15 \text{ k}\Omega$, $R_I = 4.5 \text{ k}\Omega \text{ typ.}$, $R_{IS} = 1 \text{ k}\Omega$, $R_V = 15 \text{ k}\Omega$. In case of reverse battery the current has to be limited by the load. Temperature protection is not active

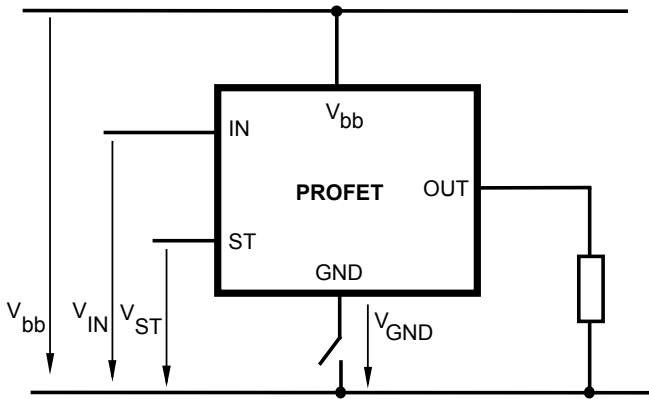
Open-load detection OUT1 or OUT2

OFF-state diagnostic condition:

$V_{OUT} > 3 \text{ V typ.}$; IN low

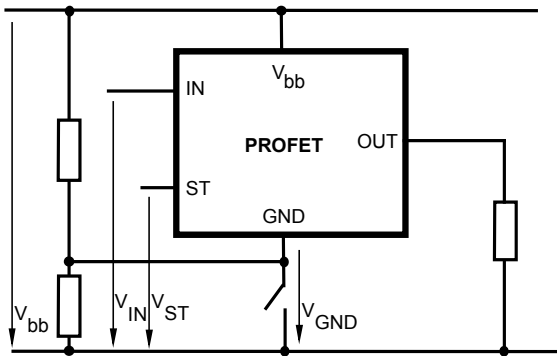


GND disconnect, each channel



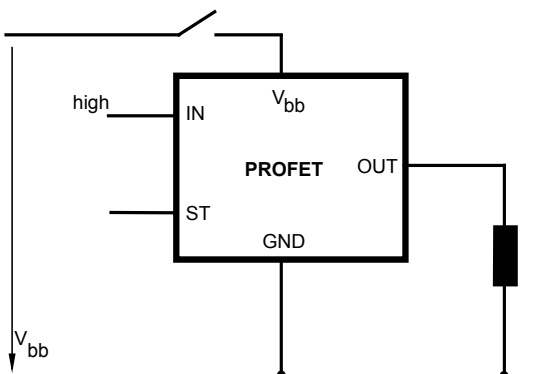
Any kind of load. In case of IN = high is $V_{OUT} \approx V_{IN} - V_{IN(T+)}$. Due to $V_{GND} > 0$, no $V_{ST} = \text{low}$ signal available.

GND disconnect with GND pull up each channel



Any kind of load. If $V_{GND} > V_{IN} - V_{IN(T+)}$ device stays off. Due to $V_{GND} > 0$, no $V_{ST} = \text{low}$ signal available.

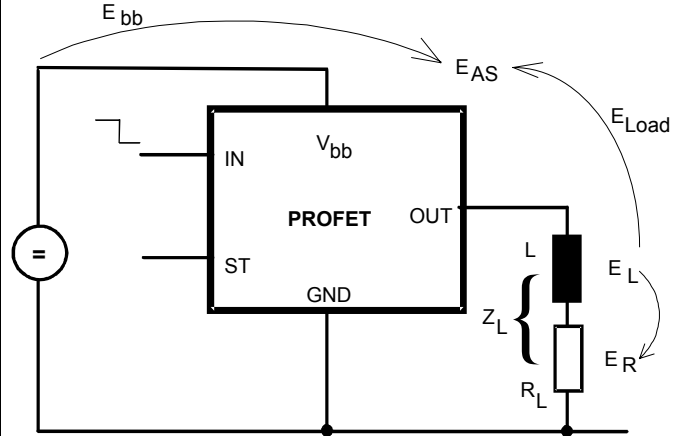
Vbb disconnect with energized inductive load, each channel



For inductive load currents up to the limits defined by Z_L (max. ratings and diagram on page 11) each switch is protected against loss of V_{bb} .

Consider at your PCB layout that in the case of V_{bb} disconnection with energized inductive load all the load current flows through the GND connection.

Inductive load switch-off energy dissipation, each channel



Energy stored in load inductance:

$$E_L = \frac{1}{2} \cdot L \cdot I_L^2$$

While demagnetizing load inductance, the energy dissipated in PROFET is

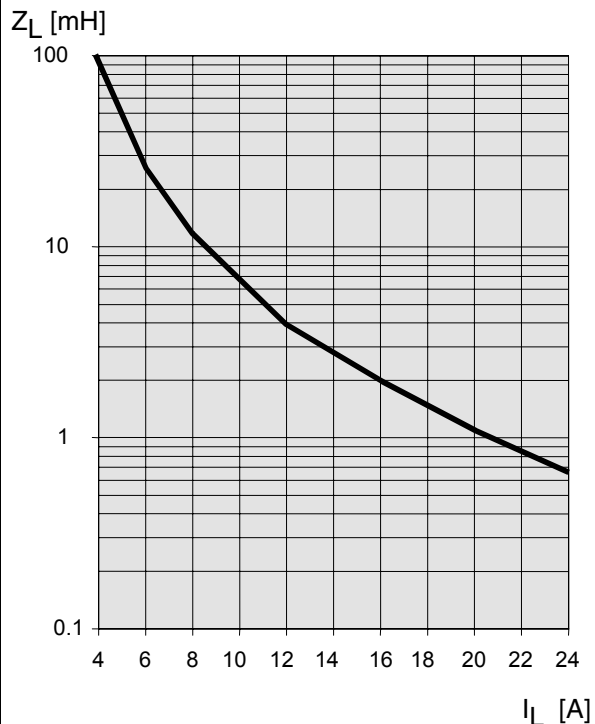
$$E_{AS} = E_{bb} + E_L - E_R = \int V_{ON(CL)} \cdot i_L(t) dt,$$

with an approximate solution for $R_L > 0 \Omega$:

$$E_{AS} = \frac{I_L \cdot L}{2 \cdot R_L} (V_{bb} + |V_{OUT(CL)}|) \ln \left(1 + \frac{I_L \cdot R_L}{|V_{OUT(CL)}|} \right)$$

Maximum allowable load inductance for a single switch off (one channel)⁴

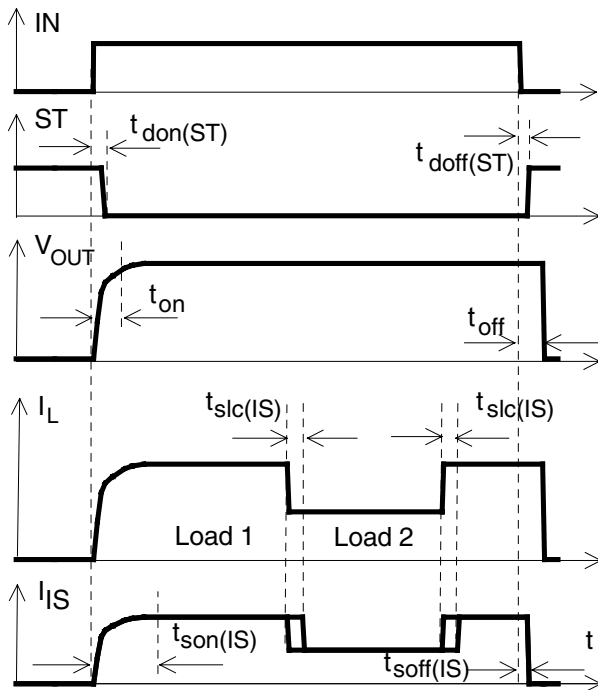
$$L = f(I_L); T_{j,start} = 150^\circ\text{C}, V_{bb} = 12\text{V}, R_L = 0 \Omega$$



Timing diagrams

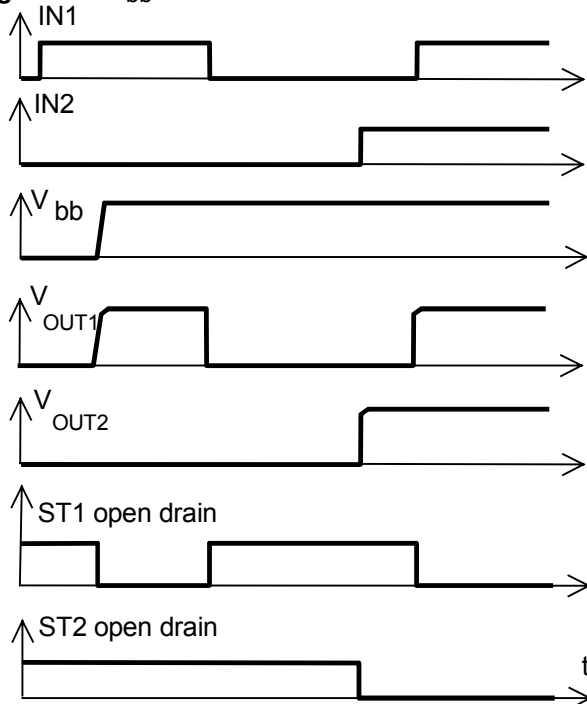
Both channels are symmetric and consequently the diagrams are valid for channel 1 and channel 2

Figure 1a: Switching a resistive load, change of load current in on-condition:



The sense signal is not valid during settling time after turn or change of load current.

Figure 1b: V_{bb} turn on:



proper turn on under all conditions

Figure 2a: Switching a resistive load, turn-on/off time and slew rate definition:

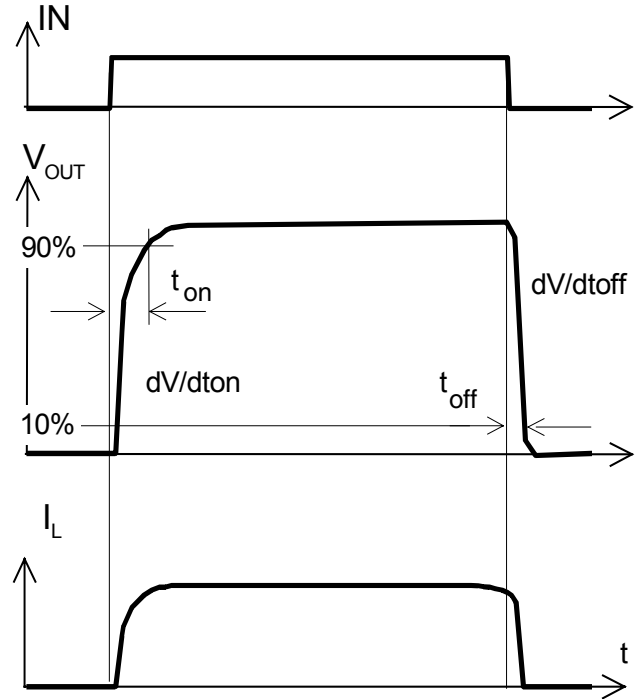
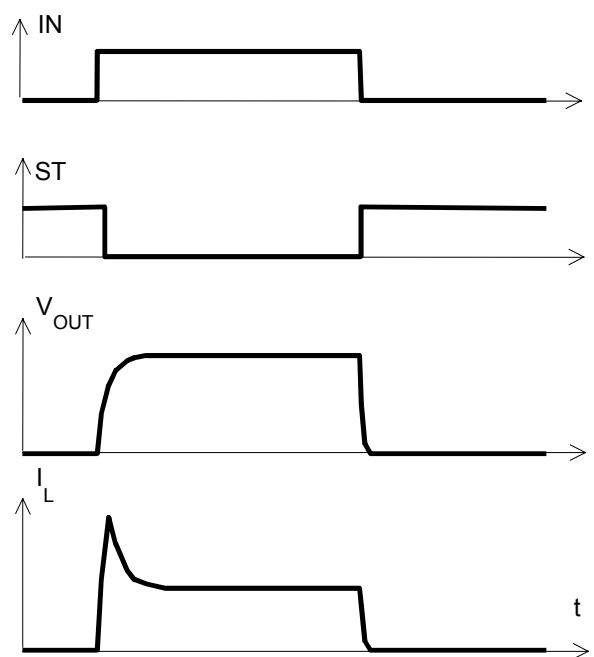


Figure 2b: Switching a lamp:



The initial peak current should be limited by the lamp and not by the current limit of the device.

Figure 2c: Switching a lamp with current limit:

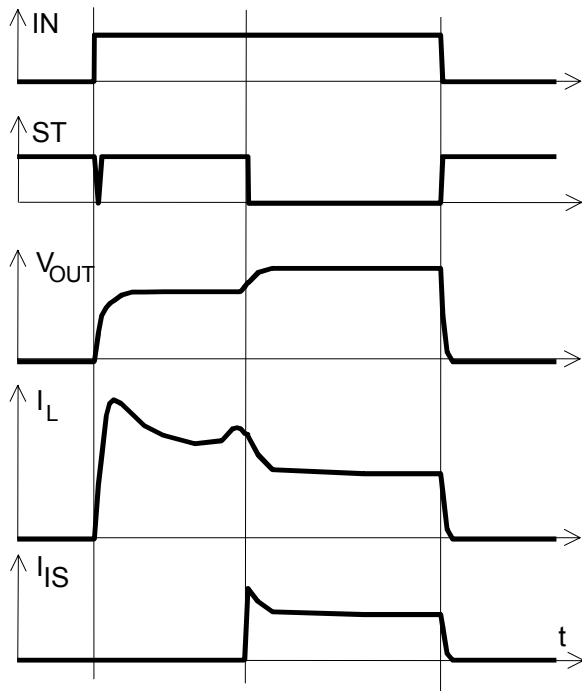
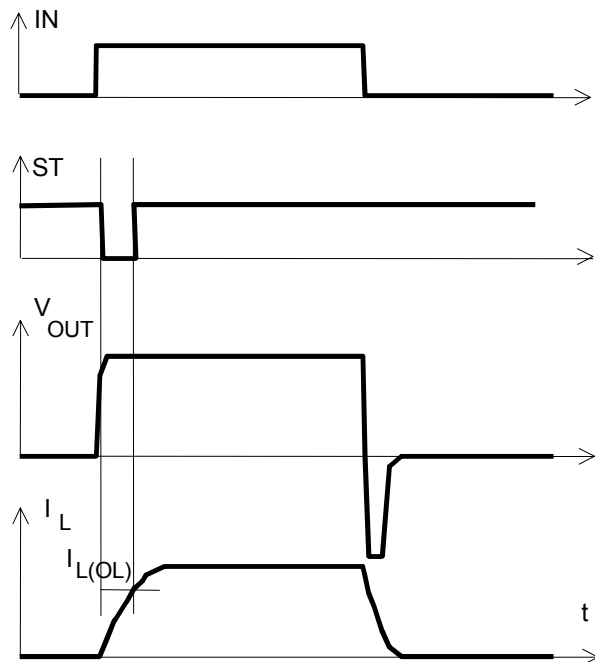
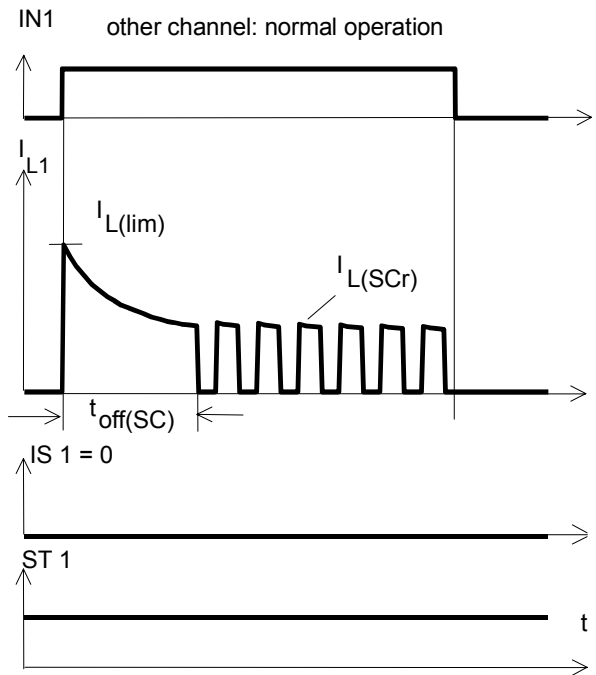


Figure 2d: Switching an inductive load



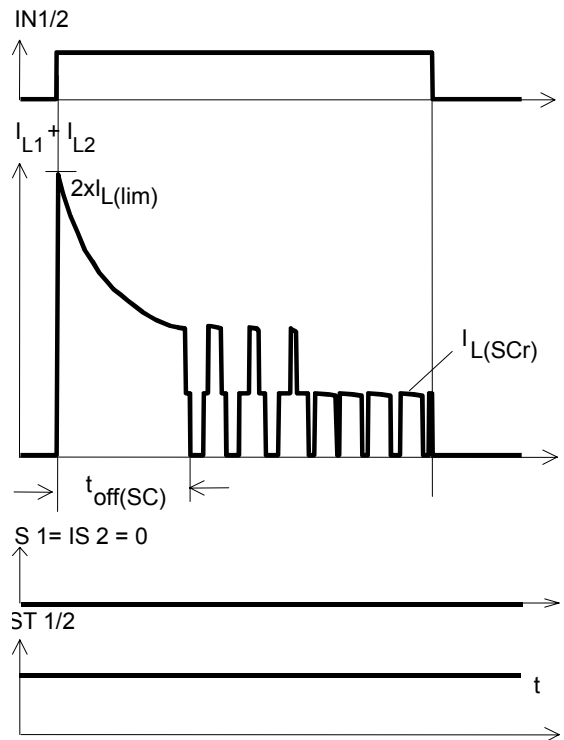
*) if the time constant of load is too large, open-load-status may occur

Figure 3a: Turn on into short circuit: shut down by overtemperature, restart by cooling



Heating up of the chip may require several milliseconds, depending on external conditions

Figure 3b: Turn on into short circuit: shut down by overtemperature, restart by cooling (two parallel switched channels 1 and 2)



ST1 and ST2 have to be configured as a 'Wired OR' function ST1/2 with a single pull-up resistor.

Figure 4a: Overtemperature:
Reset if $T_j < T_{jt}$

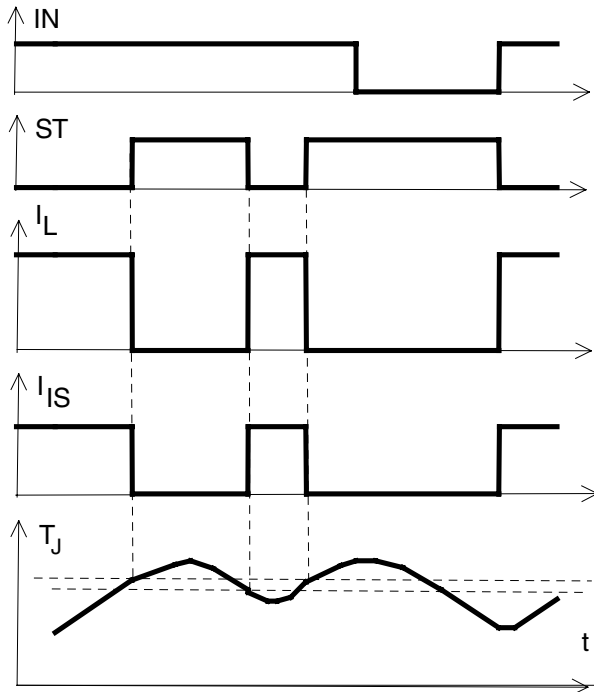


Figure 5a: Open load: detection (with R_{EXT}),
turn on/off to open load

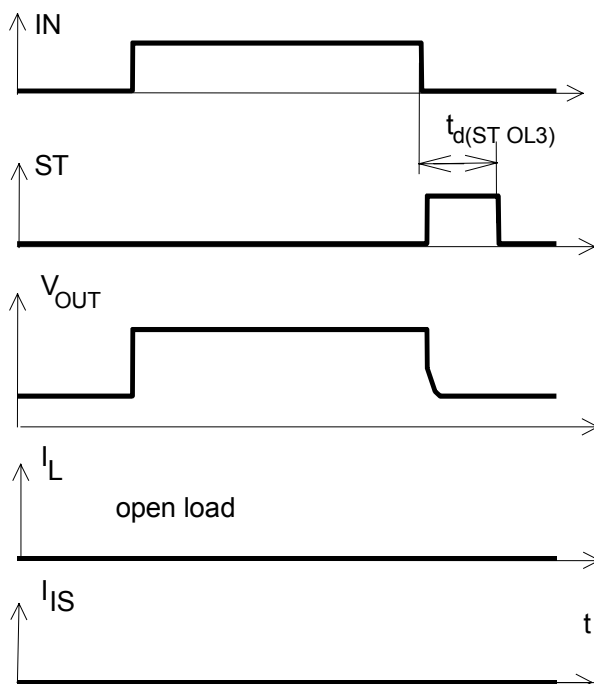


Figure 6a: Undervoltage:

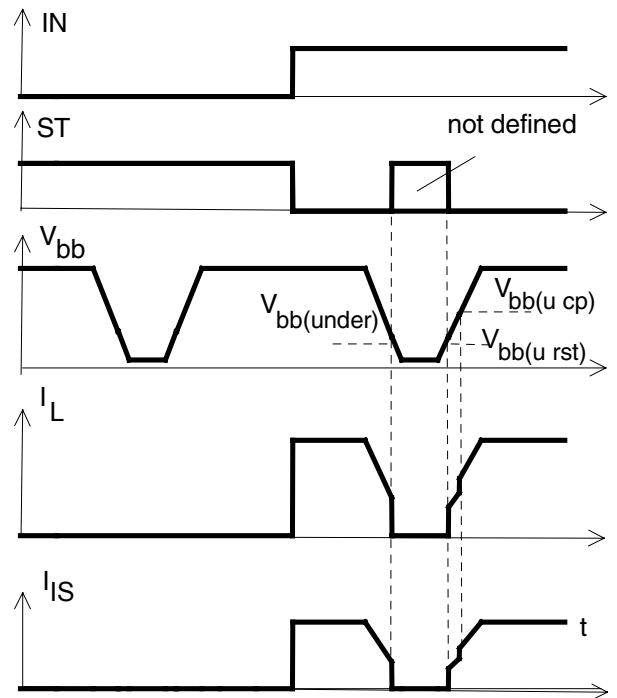
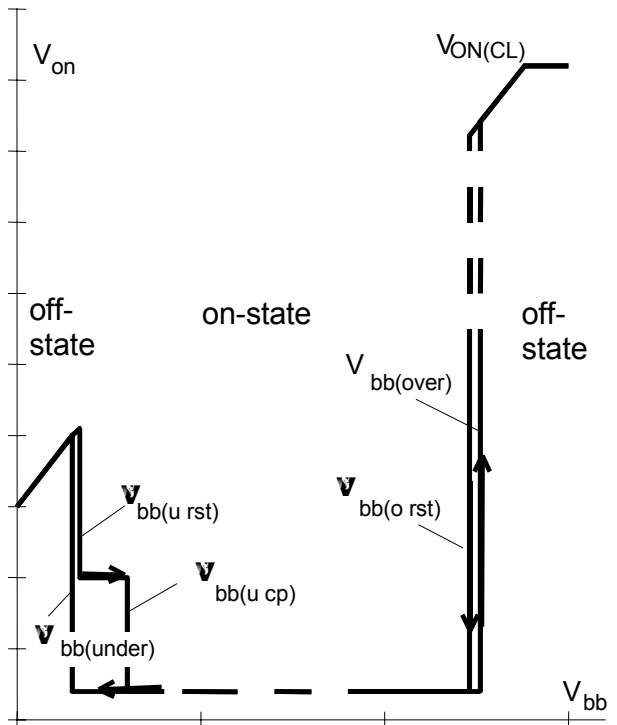


Figure 6b: Undervoltage restart of charge pump



charge pump starts at $V_{bb(ucp)} = 4.7 \text{ V typ.}$

Figure 7a: Overvoltage:

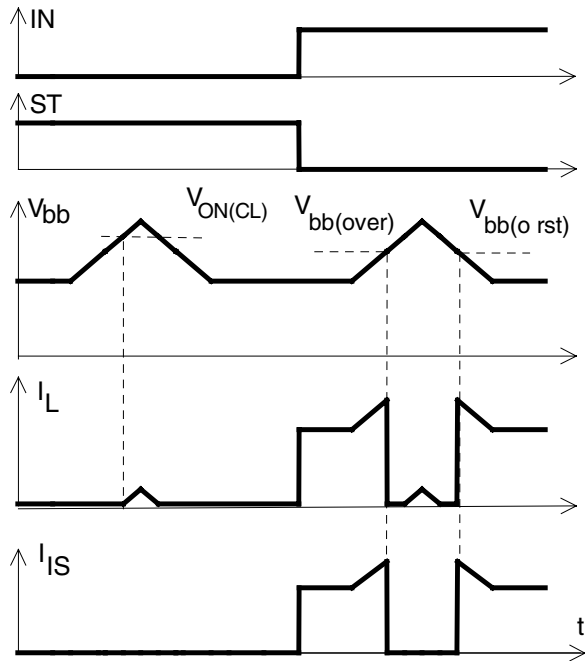


Figure 8b: Current sense ratio:

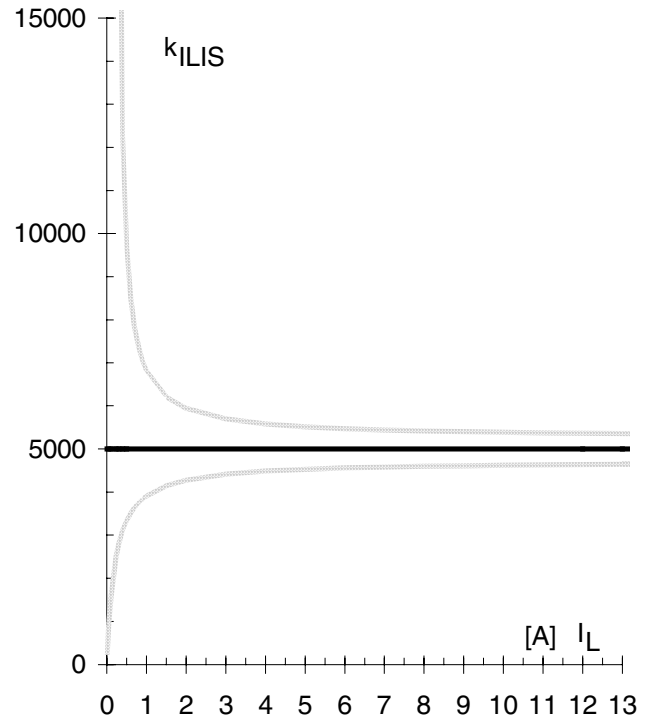


Figure 8a: Current sense versus load current²¹:

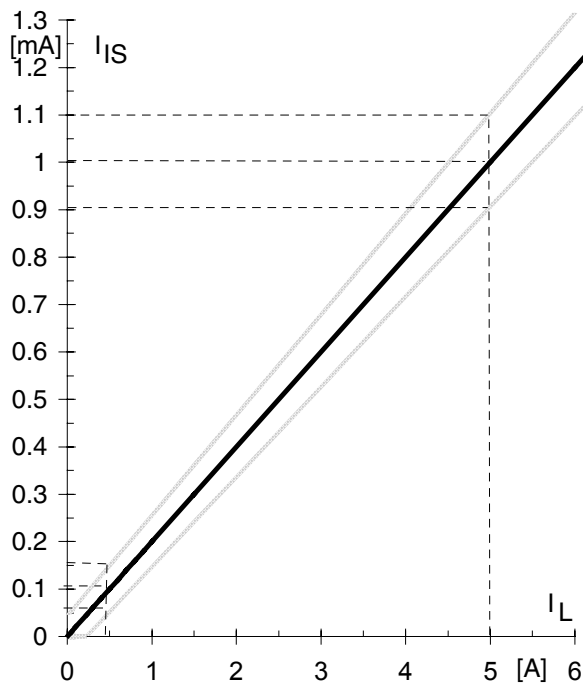
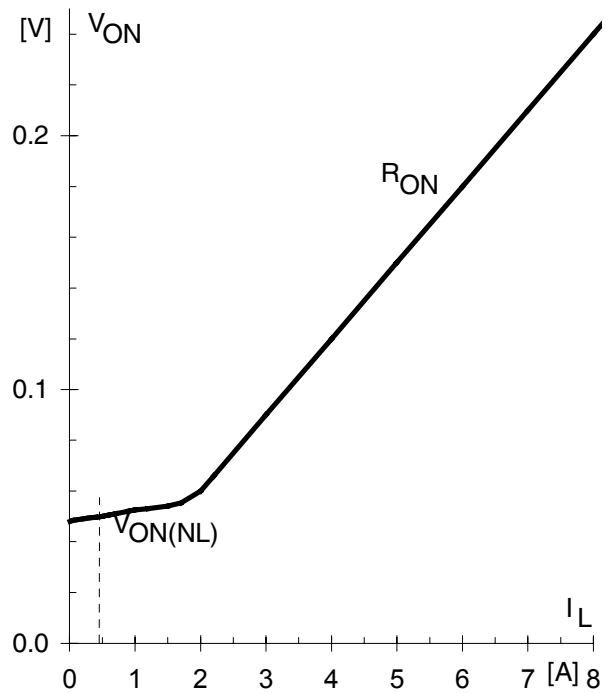


Figure 9a: Output voltage drop versus load current:



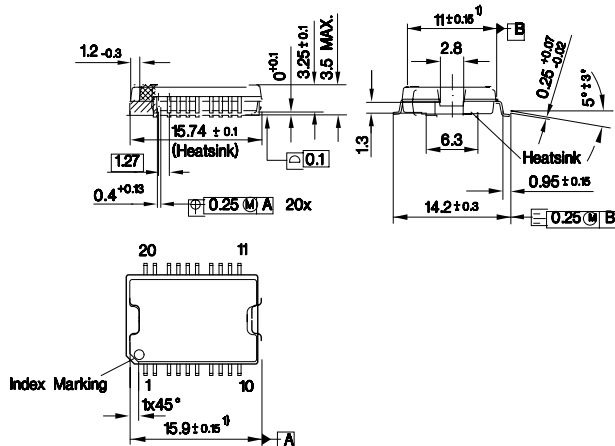
²¹ This range for the current sense ratio refers to all devices. The accuracy of the k_{ILIS} can be raised at least by a factor of two by matching the value of k_{ILIS} for every single device.

Package and Ordering Code

Standard: P-DSO-20-12 (Power SO 20)

Sales Code	BTS 840
Ordering Code	tbd

All dimensions in millimetres



1) Does not include plastic or metal protrusion of 0.15 max. per side

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